## MPQ3906

# PNP SILICON QUAD TRANSISTOR



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## **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR MPQ3906 type is comprised of four independent PNP silicon transistors mounted in a 14-pin DIP, designed for general purpose amplifier and switching applications.





MAXIMUM RATINGS: (T <sub>A</sub> =25°C)	SYMBOL		UNITS
Collector-Base Voltage	$V_{CBO}$	40	V
Collector-Emitter Voltage	$V_{CEO}$	40	V
Emitter-Base Voltage	$V_{EBO}$	5.0	V
Continuous Collector Current	I <sub>C</sub>	200	mA
Power Dissipation (per transistor)	$P_{D}$	500	mW
Power Dissipation (total package)	$P_{D}$	2.0	W
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stq</sub>	-65 to +150	°C

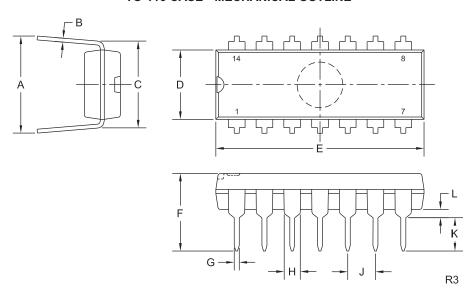
Storage Junction Temperature	<sup>I</sup> J <sup>, I</sup> stg	-65 10	) +150	30
TEST CONDITIONS	SISTOR: (T <sub>A</sub> =25° Min	°C) <b>TYP</b>	MAX	UNITS
				nA
V <sub>EB</sub> =4.0V			50	nA
I <sub>C</sub> =10μA	40			V
I <sub>C</sub> =1.0mA	40			V
I <sub>E</sub> =10μA	5.0			V
I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA			0.25	V
I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA			0.85	V
$V_{CE}$ =1.0V, $I_{C}$ =0.1mA	40			
$V_{CE}$ =1.0V, $I_{C}$ =1.0mA	60			
$V_{CE}$ =1.0V, $I_{C}$ =10mA	75			
$V_{CE}$ =20V, $I_{C}$ =10mA, f=100MHz	200			MHz
$V_{CB}$ =5.0V, $I_{E}$ =0, f=140kHz			4.5	pF
$V_{BE}$ =0.5V, $I_{C}$ =0, f=140kHz			10	pF
$V_{BE}$ =0.5V, $I_{C}$ =10mA, $I_{B1}$ =1.0mA		43		ns
I <sub>C</sub> =10mA, I <sub>B1</sub> =I <sub>B2</sub> =1.0mA		155		ns
	CHARACTERISTICS PER TRANS TEST CONDITIONS V <sub>CB</sub> =30V V <sub>EB</sub> =4.0V I <sub>C</sub> =10μA I <sub>C</sub> =1.0mA, I <sub>B</sub> =1.0mA I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA V <sub>CE</sub> =1.0V, I <sub>C</sub> =0.1mA V <sub>CE</sub> =1.0V, I <sub>C</sub> =1.0mA V <sub>CE</sub> =1.0V, I <sub>C</sub> =1.0mA V <sub>CE</sub> =20V, I <sub>C</sub> =10mA, f=100MHz V <sub>CB</sub> =5.0V, I <sub>C</sub> =0, f=140kHz V <sub>BE</sub> =0.5V, I <sub>C</sub> =0, f=140kHz	CHARACTERISTICS PER TRANSISTOR: (TA=25' TEST CONDITIONS MIN VCB=30V VEB=4.0V IC=10µA 40 IC=1.0mA 40 IC=1.0mA, IB=1.0mA IC=10mA, IB=1.0mA VCE=1.0V, IC=0.1mA 40 VCE=1.0V, IC=1.0mA 60 VCE=1.0V, IC=1.0mA 75 VCE=20V, IC=10mA, f=100MHz 200 VCB=5.0V, IC=0, f=140kHz VBE=0.5V, IC=10mA, IB=1.0mA	CHARACTERISTICS PER TRANSISTOR: (T <sub>A</sub> =25°C) TEST CONDITIONS  V <sub>CB</sub> =30V  V <sub>EB</sub> =4.0V  I <sub>C</sub> =10µA  I <sub>C</sub> =1.0mA  I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA  I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA  V <sub>CE</sub> =1.0V, I <sub>C</sub> =0.1mA  V <sub>CE</sub> =1.0V, I <sub>C</sub> =1.0mA  V <sub>CE</sub> =1.0V, I <sub>C</sub> =1.0mA  V <sub>CE</sub> =1.0V, I <sub>C</sub> =1.0mA  V <sub>CE</sub> =5.0V, I <sub>C</sub> =10mA, f=100MHz  V <sub>CB</sub> =5.0V, I <sub>C</sub> =0, f=140kHz  V <sub>BE</sub> =0.5V, I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA	CHARACTERISTICS PER TRANSISTOR: (T <sub>A</sub> =25°C) TEST CONDITIONS  V <sub>CB</sub> =30V  V <sub>EB</sub> =4.0V  I <sub>C</sub> =10μA  I <sub>C</sub> =1.0mA  I <sub>E</sub> =10μA  I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA  I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA  V <sub>CE</sub> =1.0V, I <sub>C</sub> =0.1mA  V <sub>CE</sub> =1.0V, I <sub>C</sub> =1.0mA  V <sub>CE</sub> =1.0V, I <sub>C</sub> =10mA  V <sub>CE</sub> =1.0V, I <sub>C</sub> =10mA  V <sub>CE</sub> =5.0V, I <sub>C</sub> =10mA, i=100MHz  V <sub>CB</sub> =5.0V, I <sub>C</sub> =0, f=140kHz  V <sub>BE</sub> =0.5V, I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA  43

## **MPQ3906**

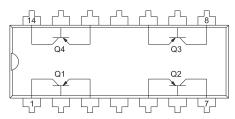
# PNP SILICON QUAD TRANSISTOR



## **TO-116 CASE - MECHANICAL OUTLINE**



# PIN CONFIGURATION



## LEAD CODE:

- Collector Q1
   Base Q1
   Emitter Q1
   No Connection
- 8) Collector Q3 9) Base Q3 10) Emitter Q3
- 4) No Connection 5) Emitter Q2 10) Emitter Q4
- 5) Emitter Q2 12) Emitter Q4 6) Base Q2 13) Base Q4 7) Collector Q2 14) Collector Q4

MARKING.	DADT	MILIMPED

DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
Α	0.310	0.390	7.9	9.9
В	0.008	0.014	0.2	0.4
С	0.310		7.9	
D	0.240	0.260	6.1	6.6
Е	0.740	0.760	18.8	19.3
F	-	0.300	-	7.6
G	0.014	0.022	0.4	0.6
Н	0.050		1.3	
J	0.100		2.5	
K	0.125	0.150	3.2	3.8
L	0.015	-	0.4	-

TO-116 (REV: R3)

R1 (4-December 2012)

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#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

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- · Custom bar coding for shipments
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- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
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- Application notes
- · Application and design sample kits
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## REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

### **CONTACT US**

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